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Configuration and Self-averaging in disordered systems

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Abstract

The main aim of this work is to present two different methodologies for configuration averaging in disordered systems. The Recursion method is suitable for the calculation of spatial or self-averaging, while the Augmented space formalism averages over different possible configurations of the system. We have applied these techniques to a simple example and compared their results. Based on these, we have reexamined the concept of spatial ergodicity in disordered systems. The specific aspect, we have focused on, is the question "Why does an experimentalist often obtain the averaged result on a single sample ?" We have found that in our example of disordered graphene, the two lead to the same result within the error limits of the two methods.

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1 Introduction : Averaging in disordered systems

The study of averaging over all possible different 'configurations' of a quenched disordered system has been a focused problem in the theory of measurements. Configuration averaging is ubiquitous both in quantum mechanics and statistical physics. For annealed disorder, where the thermal disorder driven fluctuations control the behavior of the system, the idea of spatial ergodicity is important. At finite temperatures different possible states of a canonical ensemble, for example, are occupied with Boltzmann probabilities, and observable physical properties are averaged over the ensemble. Similarly, when we wish to measure a given physical observable in a quantum system, the result of the measurement is spread over different possible states with probabilities given by squared amplitudes of their wave function projection onto those states. Our discussions will be essentially at 0K and we shall focus on frozen or quenched disorder as in a glass or disordered alloy.

During the last four decades considerable effort has gone into devising methods for carrying out averages of physical observables over different configurations realized by disordered systems.

Why do we wish to carry out such averages and is such a procedure meaningful [1]?

Let us examine a specific example. An experimentalist is carrying out energy resolved photo-emission studies on a disordered binary alloy A_xB_y. Varying the frequency of the incident photon and keeping the energy window of the excited outgoing electrons reasonably narrow, one can map out the density of states of the valence electrons for the alloy. Ideally, if the experiment is carried out on ten different samples of the same alloy, slightly different results should be obtained. Every different sample of the disordered alloy has different distributions of the A and B constituents and hence should give slightly different random results. Yet, in practice, the variation, the experimenter sees in the different samples, is well within experimental error bars. What is obtained is an average result, averaged over different realizable configurations of atomic arrangements in the alloy. The interesting fact is that averaged result is obtained in a single large sample. The same is true for other measured bulk properties like the specific heat, conductivity and different response functions.

Note that all these measured properties are global. Should there be a difference if we measure local properties with local probes ? Let us take another example of a magnetically disordered alloy AuFe (with $< 10\%$ of Fe). If we measure the magnetization of a sample, it remains zero upto liquid He temperatures. Yet, if we carry out a Mössbauer study on the same alloy, there is a clear indication of a frozen local exchange field at low temperatures, indicating the existence of non-zero local magnetization.

Configuration averaging is meaningless if we wish to look at local properties. Even here, a degree of averaging over the far environment is relevant. Although the radioactive Fe atom giving rise to the Mössbauer spectrum sits in different environments in different samples, yet experiments yield an average exchange field distribution.

We shall focus on the question, "Why does an experimentalist working on a disordered material often obtain the averaged result from a single sample ?"

2 Understanding self-averaging

Why do we observe configuration averaged results in a particular macroscopic sample ? The answer lies in the idea of spatial ergodicity or self-averaging. We shall use these terms as synonyms. Let us look at the example of a random binary alloy as illustrated in Figs.1 (a) - 1 (d). They show a number of different samples each with N atoms and its own A-B distribution. There are in all 2^N distinct configurations. Let us label each configuration by $\mathcal{C}_n$, formally the configuration average of a physical quantity $\mathcal{A}$ is

$$\ll \mathcal{A} \gg_{conf} = \frac{1}{2^N} \sum_n \mathcal{A}(\mathcal{C}_n)\gamma(\mathcal{C}_n) \tag{1}$$

where $\gamma(\mathcal{C}_n)$ is the number of times a given configuration $\mathcal{C}_n$ occurs in the collection (space) of configurations shown in Fig.1(a)-(d). Now, if $N \to \infty$ then $\gamma(\mathcal{C}_n)/2^N$ is the probability associated with the configuration and

$$\ll \mathcal{A} \gg_{conf} = \sum_n \mathcal{A}(\mathcal{C}_n)\mathcal{P}r(\mathcal{C}_n) \tag{2}$$

Let us now take a large single sample with 2^N atoms and partition it into subsystems each with N atoms. The spatial average taken over this one single sample is :

$$\ll \mathcal{A} \gg_{spat} = (1/2^N) \sum_{n=1}^{2^N} \mathcal{A}(\vec{r}_n) \tag{3}$$

where $\vec{r}$ denotes the positions of the atoms. We shall now partition the sample as shown in Fig.1 (e) and group these sites into microsystems of size N atoms, so there are $2^N/N$ such partitions which we shall call $\mathcal{C}'_n$, then

$$\ll \mathcal{A} \gg_{spat} = (N/2^N) \sum_{m=1}^{2^N/N} \frac{1}{N} \sum_{m \in \mathcal{C}'_m} \mathcal{A}(\vec{r}_m) \tag{4}$$

In the collection $\mathcal{C}'_m$ all distributions are not distinct. Assume that there are $\gamma(\mathcal{C}'_m)$ identically distributed microsystems, then the above equation can be written as :

$$\ll \mathcal{A} \gg_{spat} = (N/2^N) \sum_{m=1} \mathcal{A}(\mathcal{C}'_m)\gamma(\mathcal{C}'_m) \tag{5}$$

If we now we let $N \to \infty$ then we get :

$$\ll \mathcal{A} \gg_{spat} = \sum_{m=1} \mathcal{A}(\mathcal{C}'_m)\mathcal{P}r(\mathcal{C}'_m) \tag{6}$$

Is it then true that it follows from Eqs. (1) and (5) that the configuration average taken over many different samples is the same as the spatial average over a single sample ? The answer is in general in the negative. We should note that :

(i) The statement is untrue for any finite system.

(ii) The statement remains true if, as $N \to \infty$ in such a way that each partition of the single sample also becomes infinitely large, but for every configuration (shown on Fig.1 (a)-1 (d)) there is a one-to-one correspondence with a partition shown in Fig.1 (e) and vice versa. This is a very strong statement and is known as the "Spatial Ergodic Principle" for quenched disordered systems.

(iii) If these averages diverge as $N \to \infty$, but the variance diverges faster, then there is no point in talking about averages, since the fluctuations about the average dominate. Example of such a system is the intensity of starlight after it passes through a disordered dielectric medium. The fluctuations in intensity dominate over the average, causing star to twinkle even outside our atmosphere. [2]. The same holds for conductance fluctuations in disordered media.[3].

Although numerous very detailed and rigorous works exist on temporal ergodicity [4, 5], a similar detailed exposition on spatial ergodicity is scarce. The concept of spatial ergodicity is a conjecture; its mathematical proof involves many stringent pre-conditions. Many systems do not satisfy them and therefore are not spatially ergodic. In order to develop an algorithm for configuration averaging, we have to be careful to ensure that the assumption of spatial ergodicity remains valid. The aim of this paper is to introduce two different numerical techniques : one of which explicitly calculates the spatial average and the other the configuration average and then compare the two results for a simple example of disordered graphene. We have specifically chosen a two-dimensional model, as prior experience tells us that non-ergodicity appears more often in lower dimensional systems [3].

3 Spatial averaging and the Recursion Method

Our systems of interest are disordered systems, and consequently the Bloch Theorem fails to hold. Strictly speaking reciprocal space approaches are invalid. There has been supercell approaches, where the local disorder has been incorporated in a large supercell and periodic boundary conditions were imposed on the surfaces of the supercell. Unfortunately, the fact that whenever there are imposed periodicities, the spectral function always leads to sharp bands and the disorder induced lifetimes which gives a spread to the bands cannot be obtained. In all such approaches one has to introduce a small imaginary part to the energy to smoothen these sharp features and this is introduced arbitrarily 'by hand'. We have briefly discussed the effects of the superlattice approach and its attendant artificial periodicity imposed in Appendix 1.

We turn instead to real space techniques. We first propose a methodology to deal with spatial averaging in disordered systems. It has been argued that many of the properties of solids are crucially dependent on the local chemistry of the atoms constituting the solid [6]. For such properties a Black Body Theorem essentially states that the very far environment of an atom in a solid has very little influence on its local chemistry. This local environment approach to the electronic structure of solids requires an alternative to band theory for solving the Schrödinger equation. Band theory is invalid in disordered systems. Physics is better understood by means of a solution that explicitly accounts for the role of local environment. The recursion method introduced by Haydock *et al*[7] is a lucid approach in this direction. It expresses the Hamiltonian in a form that couples an atom to its first nearest neighbor, then through them to its distant neighbors and so on. Mathematically, a new orthonormal basis set $|n\rangle$ is constructed by a three term recurrence formula to make the Hamiltonian tridiagonal.The starting state $|0\rangle$ of recursion is :

$$|0\rangle = \frac{1}{\sqrt{N}} \sum_i \ \eta_i |R_i\rangle \tag{7}$$

where, η_i take the values ± 1 randomly, so that :

$$\langle 0|G(z)|0\rangle \quad = \frac{1}{N} \left\{ \sum_i \eta_i^2 \langle R_i|G(z)|R_i\rangle + \sum_i \sum_j \eta_i \eta_j \langle R_i|G(z)|R_j\rangle \right\}$$

Since $\eta_i^2 = 1$ and the second term $O(\sqrt{N})$, the spatial average of the total density of states (TDOS) is :

$$-\frac{1}{\pi} \Im m \ TrG(E + i0) = \ll n(E) \gg_{\rm sp} \tag{8}$$

The whole set of orthonormal states are generated by the following three term recurrence relation:

$$\beta_{n+1}|n+1\rangle = H|n\rangle - \alpha_n|n\rangle - \beta_n|n-1\rangle \tag{9}$$

Since we cannot apply Bloch theorem for systems where periodic symmetry is lost, we take recourse to an alternative approach of obtaining physical properties from the averaged resolvent. Haydock et al. [7] have showed that using Eq. (9) we can expand the resolvent as a continued fraction :

$$\ll G_{RR}(z) \gg_{\rm sp} = \cfrac{1}{z-\alpha_0-\cfrac{\beta_1^2}{z-\alpha_1-\cfrac{\beta_2^2}{z-\alpha_2-\cfrac{\beta_3^2}{z-\alpha_3-\cfrac{\beta_4^2}{z-\alpha_4-T(z)}}}}} \tag{10}$$

In practice, the continued fraction is evaluated to a finite number of steps.

3.1 The far environment : terminators

Right at the start we chose the real space algorithm over mean-field and supercell approaches because we do not wish to introduce artificial periodicity and miss out on the effects of long-ranged disorder. The problem with any numerical calculation is that we can deal with only a finite number of operations. In the recursion algorithm, we can go up to a finite number of steps and if we stop the recursion, or impose periodicity this would lead to exactly what we wish to avoid. The analysis of the asymptotic part of the continued fraction is therefore of prime interest to us. This is the "termination" procedure discussed by Haydock and Nex[8], Luchini and Nex[9], Beer and Pettifor[10] and in considerable detail by Viswanath and Muller [11]. This terminator $T(z)$ which accurately describes the far environment, must maintain the herglotz analytical properties. We have to incorporate not only the singularities at the band edges, but also those lying on the compact spectrum of H. Viswanath and Muller [11] have proposed a terminator :

$$T(z) = \frac{2\pi(E_m)^{(p+2q+1)/2}}{B\left(\frac{p+1}{2}, 1+q\right)}|z-E_0|^p\left\{(z-E_1)(E_2-z)\right\}^q \tag{11}$$

The spectral bounds are at E_1 and E_2 with square-root singularities, $E_m^2 = E_1E_2$ and there is a cusp singularity at E_0 if $p = 1, q = 1$ or infra-red divergence if $p = -1/2, q = 0$. E_0 sits on the compact

spectrum of H. Magnus [12] has cited a closed form of the convergent continued fraction coefficients of the terminator :

$$\begin{aligned} \beta_{2n}^2 &= E_m^2 \, \frac{4n(n+q)}{(4n+2q+p-1)(4n+2q+p+1)} \\ \beta_{2n+1}^2 &= E_m^2 \, \frac{(2n+2p+1)(2n+2q+p+1)}{(4n+2q+p+1)(4n+2q+p+3)} \end{aligned} \tag{12}$$

The parameters of the terminator are estimated from the asymptotic part of the continued fraction coefficients calculated from our recursion. Viswanath-Müller termination was used and seamlessly enmeshed with the calculated coefficients as shown in Fig. 2 (a) and 2 (b). In this way both the near and the far environments are accurately taken into account.

4 Ensemble averaging and the Augmented Space technique

The augmented space or configuration space method had been proposed as early as 1973 by Mookerjee [13]. Some of the most successful beyond single-site, mean-field averaging techniques in random systems are based on this method : e.g. the travelling Cluster Approximation (CA) [14] and the itinerant Coherent Potential Approximation (CPA) [15]. In this approach we work not only with individual configurations of the sample but also with collection of all possible configurations. Let us examine the basic concepts in this methodology.

Suppose we measure a property of the system which is not disordered. In that case we may carry out repeated measurements of the property N and get a set of results which are all the same within error bars : $n \pm \delta$ and we get this with probability one. When the system is disordered the same set of measurements yield a set of values $n_1, n_2 \ldots n_m \pm \delta$ with probabilities $p_1, p_2 \ldots p_m$. We cannot associate a scalar quantity with this property. Instead, we associate an operator $\tilde{N}$ whose eigenvalues are the measured quantities and whose spectral density is the probability density of $\tilde{N}$.

Take for example, a random variable n_R, which takes the value 1 if the site R is occupied by a A type atom with probability x and 0 if the site R is occupied by a B type atom with probability y. The next problem is the inverse problem of recursion. There the tri-diagonal representation of the Hamiltonian is given and the resolvent is obtained as a continued fraction. Here, the resolvent is given and by inspection,

related to the probability density :

$$P(n_R) = x\delta(n_R - 1) + y\delta(n_R) = -(1/\pi)Im\left\{\frac{x}{n_R - 1} + \frac{y}{n_R}\right\} \quad (13)$$

$$= -(1/\pi)Im\frac{1}{n_R - x - \dfrac{xy}{n_R - y}} \quad (14)$$

So

$$\tilde{N} = \begin{pmatrix} x & \sqrt{xy} \\ \sqrt{xy} & y \end{pmatrix}$$

The eigenvalues are 0 and 1 as expected. The above representation is in a basis :

$\square_R = \sqrt{x}|0\rangle + \sqrt{y}|1\rangle \;\; ; \blacksquare_R = \sqrt{y}|0\rangle - \sqrt{x}|1\rangle$

Each member of the basis, is a 'configuration' of $\tilde{N}$ at R. For later convenience we choose the first to be the 'reference configuration' and the second to be a disorder induced 'configuration fluctuation' whose creation from the reference configuration is described by $b_R^\dagger$. Since the disorder is binary and each site can have only one fluctuation, these fluctuations behave like fermions :

$$b_R^\dagger \blacksquare_R = 0 \quad ; \quad b_R \square_R = 0$$

Each site R has an operator and a configuration space associated with it. The system of N sites then has a configuration space $\Phi = \prod^{\otimes} \phi_R$ of rank 2^N. The number of fluctuations in a configuration is called its 'cardinality' and the sequence of sites where they occur is called its 'cardinality sequence'. Some typical configurations are shown below with their cardinalities and cardinality sequences :

$\left\{\square_{R_1} \; \square_{R_2} \; \square_{R_3} \; \square_{R_4} \; \square_{R_5} \; \square_{R_6} \; \ldots\right\}$ card = 0, card. sequence = $\{\emptyset\}$

$\left\{\blacksquare_{R_1} \; \square_{R_2} \; \blacksquare_{R_3} \; \square_{R_4} \; \square_{R_5} \; \blacksquare_{R_6} \ldots\right\}$ card = 3, card. sequence = $\{R_1, R_3, R_6\}$

$\left\{\square_{R_1} \; \square_{R_2} \; \blacksquare_{R_3} \; \blacksquare_{R_4} \; \square_{R_5} \; \square_{R_6} \ldots\right\}$ card = 2, card. sequence = $\{R_3, R_4\}$

These operators are in the 'configuration' space Φ of rank 2^N. They may be written as :

$$\tilde{N}_R = I + (y - x)b_R^\dagger b_R + \sqrt{xy}(b_R^\dagger + b_R)$$

The next thrust in this approach came with the Augmented Space Theorem stated by Mookerjee [13]. We shall try to understand this by an example :

$$P(n_R) \;=\; (-1/\pi)\,\Im m\,\langle\emptyset|\Big((n_R+\imath 0)I \;-\; N_R\Big)^{-1}|\emptyset\rangle \;=\; (-1/\pi)\,\Im m\; g(z) \tag{15}$$

where $g(z) = \langle\emptyset|(z\tilde{I} - \tilde{N}_R)^{-1}|\emptyset\rangle$ is the resolvent of $\tilde{N}_R$

and

$$|\emptyset\rangle \;=\; \Big|\square_{R_1}\quad \square_{R_2}\quad \square_{R_3}\quad \square_{R_4}\quad \square_{R_5}\quad \square_{R_6}\quad \ldots\Big\rangle$$

Let $f(n_1, n_2 \ldots n_k \ldots)$ be a well behaved function of the set of independent random variables $\{n_1, n_2, \ldots n_k \ldots\}$, then

$$\begin{aligned} \ll f(n_1, n_2 \ldots) \gg \;&=\; \int dn_1 \int dn_2 \ldots f(n_1, n_2 \ldots) P(n_1) P(n_2) \ldots \\ &=\; \oint dz_1 \oint dz_2 \ldots f(z_1, z_2 \ldots)\; g(z_1) g(z_2) \ldots \end{aligned}$$

Using the completeness of the eigenbasis of $\{\tilde{N}_R\}$

$$\begin{aligned} \langle\emptyset| \oint dz_1 \oint dz_2 \ldots f(z_1, z_2, \ldots) \int d\rho(\mu_1) \int d\rho(\mu_2) \ldots |\mu_1, \mu_2 \ldots\rangle\langle\mu_1, \mu_2 \ldots| \ldots \\ \prod (zI - N_R)^{-1} \int d\rho(\mu_1') \int d\rho(\mu_2') \ldots |\mu_1', \mu_2' \ldots\rangle\langle\mu_1', \mu_2' \ldots|\emptyset\rangle \end{aligned}$$

Now using the orthogonality of the eigenstates of $\{\tilde{N}_R\}$:

$$\begin{aligned} &= \langle\emptyset| \int d\rho(\mu_1) \int d\rho(\mu_2) \ldots |\mu_1, \mu_2 \ldots\rangle \left[\oint dz_1 \oint dz_2 f(z_1, z_2, \ldots) \prod (z - \mu_k)^{-1}\right] \langle\mu_1, \mu_2 \ldots|\emptyset\rangle \\ &= \langle\emptyset| \left[\int d\rho(\mu_1) \int d\rho(\mu_2) \ldots |\mu_1, \mu_2 \ldots\rangle f(\mu_1, \mu_2, \ldots)\langle\mu_1, \mu_2 \ldots\right] |\emptyset\rangle \end{aligned}$$

Finally,

$$\ll f(n_1, n_2 \ldots) \gg = \langle\emptyset|\widetilde{f}(\tilde{N}_1, \tilde{N}_2 \ldots)|\emptyset\rangle$$

The operator on the right-hand side is the same operator function of the operators $N_1, N_2, \ldots$ as the function f was of $n_1, n_2, \ldots n_3$. This is the central result of the augmented space technique : configuration

averages are specific matrix elements in the full augmented space, which carries not only the information about the underlying lattice, but also how that lattice is randomly decorated with the two constituents subject to their concentrations.

Let us return to the disordered binary alloy described by the Hamiltonian :

$$\begin{aligned} H &= \sum_R \left[\epsilon_B + (\epsilon_B - \epsilon_A) n_R\right] \; a_R^\dagger a_R \; + \ldots \\ &\ldots + \sum_R \sum_\chi \left[t^{BB}(\chi) + t^{(2)}(\chi) \; n_R \; n_{R+\chi} + t^{(1)}(\chi) \; (n_R + n_{R+\chi})\right] \; a_{R+\chi}^\dagger a_R \end{aligned} \tag{16}$$

Here, $t^{(1)}(\chi) = t^{AB}(\chi) - t^{BB}(\chi)$ and $t^{(2)}(\chi) = t^{AA}(\chi) + t^{BB}(\chi) - 2t^{AB}(\chi)$, where $\chi = R - R'$.

This Hamiltonian is an operator in a Hilbert space $\mathcal{H}$ spanned by the denumerable basis $\{|R\rangle\}$. We now turn to the augmented space formalism and associate with each random variable n_R an operator $\tilde{N}_R$ such that its eigenvalues are the values attained by n_R and the density of states of N_R is the probability density of n_R for attaining its values. For binary randomness (e.g. n_R takes the values 0 and 1 with probabilities x and y) the space ϕ_R in which N_R acts is of rank 2.

The 'augmented Hamiltonian' can then be written as :

$$\begin{aligned} \widetilde{H} &= \sum_R \left[\ll \epsilon \gg + \Delta \left\{(y-x) b_R^\dagger b_R + \sqrt{xy}(b_R^\dagger + b_R)\right\}\right] \; a_R^\dagger a_R \; + \ldots \\ &\ldots + \sum_R \sum_\chi \left[\ll t(\chi) \gg + \sqrt{xy} t^{(2)}(\chi)(b_R^\dagger + b_{R+\chi}) \; + t^{(1)}(\chi)(b_R^\dagger + b_{R+\chi})\right] \; a_{R+\chi}^\dagger a_R \end{aligned} \tag{17}$$

Here, $a_R, a_R^\dagger$ are electron destruction and creation operators, $\Delta = (\epsilon_B - \epsilon_A)$.

The Augmented Space Theorem[16] then leads to :

$$\ll G(R, R', z) \gg = \langle R \otimes \{\emptyset\} | (z\tilde{I} - \widetilde{H})^{-1} | R' \otimes \{\emptyset\} \rangle \tag{18}$$

The result is significant, since we have reduced the calculation of averages to one of obtaining a particular matrix element of an operator in the configuration space of the variable. Physically, of course, the augmented Hamiltonian is the collection of all Hamiltonians. This augmented Hamiltonian is an operator in the augmented space $\Psi = \mathcal{H} \otimes \Phi$ where $\mathcal{H}$ is the space spanned by the tight binding basis and Φ the full space of all configurations. The result is exact. Approximations can now be introduced in the actual calculation of this matrix element in a controlled manner.

The same recursion method used for spatial averaging (Haydock et al. [7]) is ideally suited for obtaining matrix elements in augmented space. Since configuration averaging is an intrinsically difficult problem, we must pay the price for the above simplification. This comes in the shape of the enormous rank of the augmented space. For some time it was thought that recursion on the full augmented space was not a feasible proposition. However, if randomness is homogeneous in the sense that $p(n_R)$ is independent of the label R, then the full augmented space has a large number of local point group and lattice translational symmetries. These have been utilized to reduce vastly the rank of the effective space on which the recursion can be carried out. Recursion on augmented space can be done now with ease, even on desktop computers.

5 A simple application to disordered graphene

It would be interesting to apply our two different techniques on a simple, yet interesting system. We have chosen disordered graphene. The choice of this example was both because of interest in graphene and because non-ergodicity seems to be more probable in lower dimensional systems [3]. Disorder in graphene can significantly modify the electronic properties because the interplay between electron-electron interactions and the disorder controls the low energy regime of electrons in graphene [17, 18, 19, 20]. The presence of disorder in graphene can emerge through various synthesis processes when there occurs an interaction with the substrates due to its exposed surface. Various kinds of nature of defects such as random impurities and vacancies present in graphene can change the electronic structure. Chemical substitution and irradiation are some of the effective methods to produce local disorder in graphene. In fact, recently, Pereira et al. [21] have shown the dramatic changes (such as localized zero modes, gap and pseudo-gap behavior and strong resonances) in the low energy spectrum of graphene within the tight binding approximation due to this local disorder.

With this motivation, let us introduce a simple, non-trivial model of a disordered graphene sheet. This is described by a tight-binding Hamiltonian with a single band p_z per site. Anderson [22] studied this model in his now celebrated 1958 paper and it goes under his name.

$$H = \sum_R \varepsilon_R \mathcal{P}_R + \sum_R \sum_{R'} t_{RR'} \mathcal{T}_{RR'} \tag{19}$$

Here $\mathcal{P}_R = |R\rangle\langle R|$ and $\mathcal{T}_{ij} = |R\rangle\langle R'|$ are projection and transfer operators on the space spanned by the tight-binding basis $\{|R\rangle\}$. The simplest model of a void is just the removal of an atom from a site R,

putting $t_{R'R} = 0$ and $\varepsilon_R \rightarrow -\infty$. We have used the tight-binding linear muffin-tin orbitals (TB-LMTO) technique followed by a N-th order muffin-tin orbitals (NMTO) downfolding to obtain the parameters of the single p_z orbital per site model. The pristine graphene itself is a open structure and required inclusion of three empty spheres for proper space filling. When we randomly removed carbon atoms to produce voids, the space had to be replaced by empty spheres.

The tight-binding parameters are shown in Table 1. The overlap t decays with distance. In this work we have truncated at the nearest neighbor distances. The results of TB-LMTO band structure for graphene are shown in Figs.3(a) and 3(b). For justification of p_z only downfolding, we have compared the various orbital projected partial density of states (PDOS) in Fig.3(c).

6 Results and discussion

We have applied the two above techniques : the real space recursion and augmented space to obtain the density of states (DOS) for graphene with random voids. The former yields the spatial averages, while the latter yields configuration averages. Figs.4(a) - 4(f) compare the spatial and configuration averages of three void compositions. Other than the energy resolution difference in the two methods (discussed shortly in the Appendix) our conclusion is that disordered graphene is self-averaging.

However there is a subtle point which we should comment on :

If we examine the band edges, we note that whenever there is periodicity at any scale at all, the band edges are sharp and quadratic. Long range disorder leads to band tailing. Signs of this appear in the configuration averaged results. This disorder induced band tailing has been known for decades and it would be interesting to examine if the tail states are localized or not.

Again periodicity at whatever scale leads to structure in the DOS. This is smoothened out by the disorder scattering induced complex 'self-energy'. Occasionally practitioners of super-cell techniques introduce an artificial imaginary part to the energy. This smoothes these structures too, but the procedure

Table 1: Tight-binding parameters generated by NMTO. χ_n refer to the n-th nearest neighbor vector on the lattice.

(eV)	ε	t(χ_1)	t(χ_2)	t(χ_3)
	-0.291	-2.544	0.1668	-0.1586

is entirely ad hoc. Augmented space leads to an energy dependent self-energy systematically.

It is important to note that the inverse of the imaginary part of the self-energy, called the "life time" is accessible to neutron scattering experiments. The spatial averages cannot access this "life-time" effect and it is essential to carry out configuration dependent averaging to calculate it.

Further insights into different averaging procedures is desirable. Besides, the TDOS results obtained here can be verified through scanning tunneling microscopy and the effect on the TDOS particularly at the Fermi energy / Dirac point should reflect on the electronic transport process.

7 Conclusions

We have employed two techniques, the real space recursion and augmented space to obtain the density of states for graphene with random voids. The numerical results obtained here clearly indicate that spatial ergodicity holds good for graphene with random voids.

Appendix

It will be interesting to understand why different methods have different energy resolutions. Periodicity and the Bloch Theorem leads to the labeling of quantum states by a real vector $\vec{k}$ and a supplementary band label 'n'.

$$\langle \vec{k}, n|G(z)|\vec{k}, n\rangle = \frac{1}{z - E_n(\vec{k})}$$

So that :

$$-(1/\pi)\sum_n ImG(E + i0, \vec{k}, n) = \sum_n \delta(E - E_n(\vec{k}))$$

For a fixed $\vec{k}$ this is a set of delta functions. If we abandon periodicity and adopt the augmented space formalism :

$$\begin{aligned} -(1/\pi)\sum_n Im \ll G(E + i0, \vec{k}, n) \gg &= -(1/\pi)\sum_n Im \frac{1}{E - E_n(\vec{k}) - \Sigma_r(E, \vec{k}) - i\Sigma_{im}(E, \vec{k})} \\ &= \sum_n \frac{[1/\pi\tau(E, \vec{k}, n)]}{[(E - E'_n(\vec{k})]^2 + [(1/\tau(E, \vec{k}, n)]^2} \end{aligned}$$

This spectral density comes out to be much smoother and the smoothening lifetime has its origin in scattering by disorder fluctuations. Moreover the lifetime emerges out of the calculations and no external broadening or smoothening factors are required.

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Figure Captions

Figure 1 : (a)-(d) Ensemble of macrosystems in the configuration space of a binary alloy. (e) A single macrosystem constructed out of the microsystems shown in (a)-(d).

Figure 2 : (a) Asymptotic parts of the calculated graphene Green function continued fraction coefficients obtained by recursion for 5% voids and (b) the same for 1% voids.

Figure 3 : (a) The all orbital TB-LMTO band structure for graphene.(b) The downfolded p_z bands based on the single band effective Hamiltonian. (c) The orbital projected partial density of states.

Figure 4 : (a),(b),(c):TDOS for Graphene using configuration averaging for 1, 2 and 10 % voids respectively. (d),(e),(f):TDOS for Graphene using spatial averaging for 1, 2 and 10 % voids respectively.

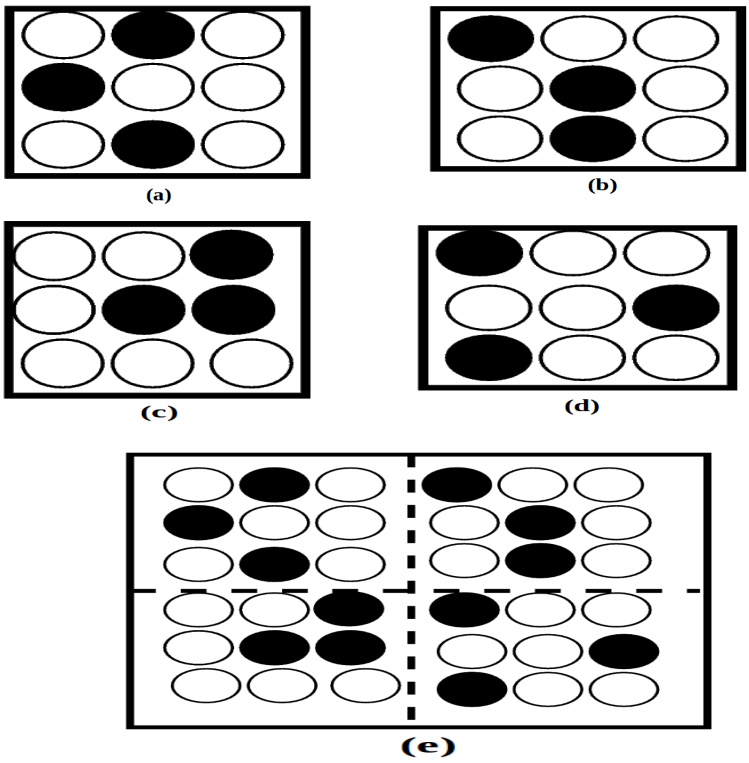


Figure 1: (a)-(d) Ensemble of macrosystems in the 'configuration space' of a binary alloy. (e) A single macrosystem constructed out of the microsystems shown in (a)-(d).

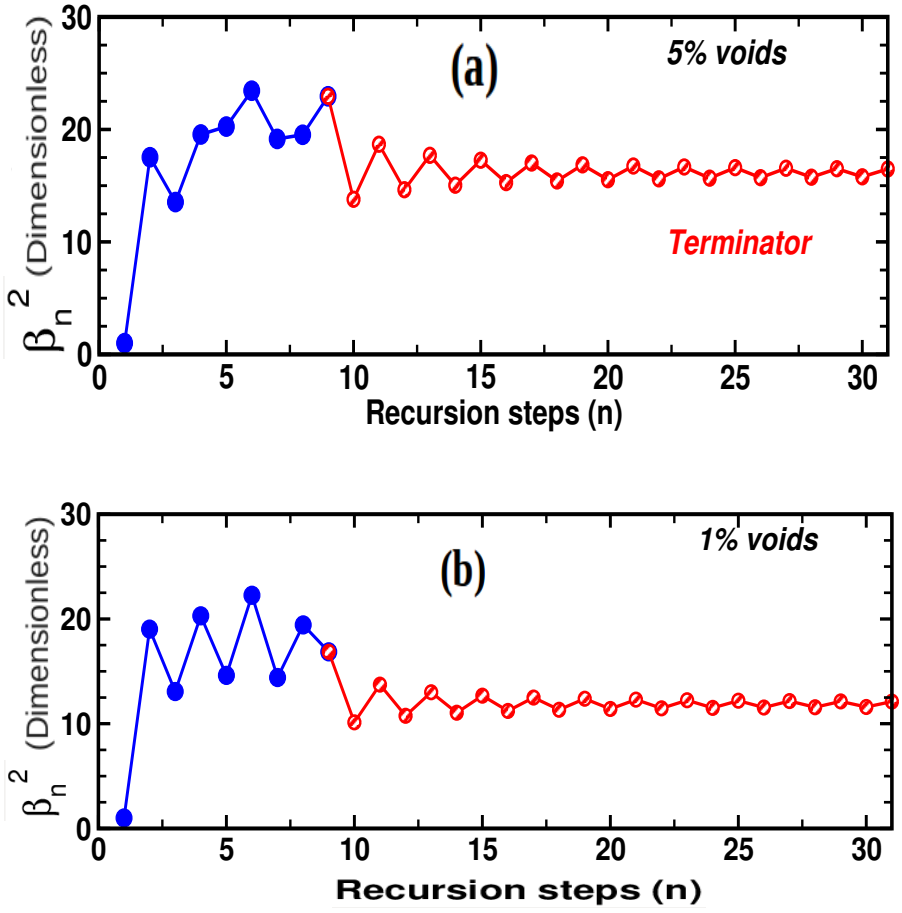
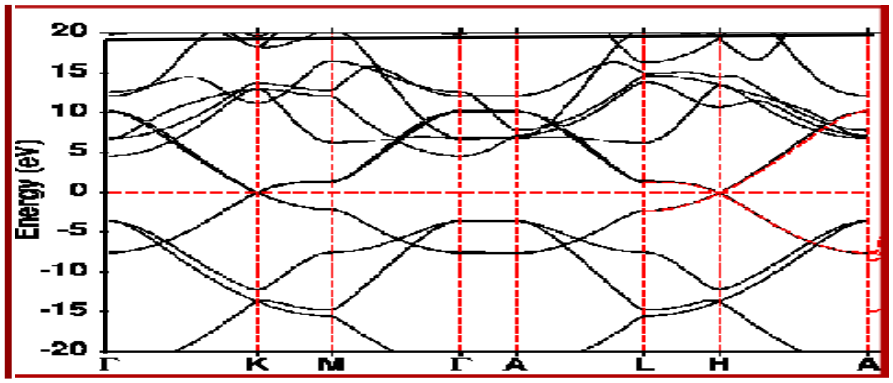
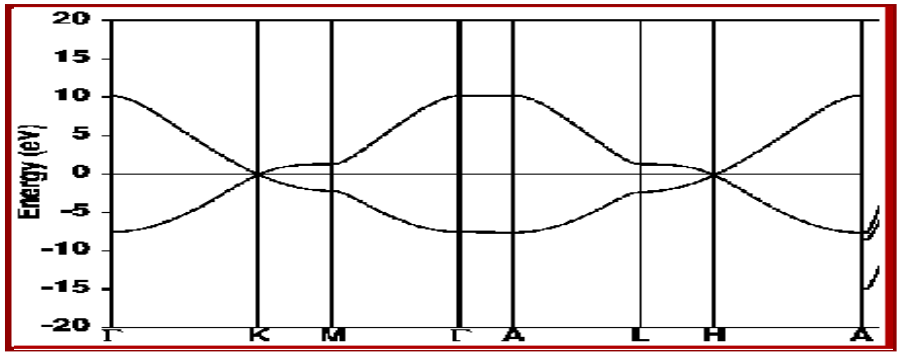


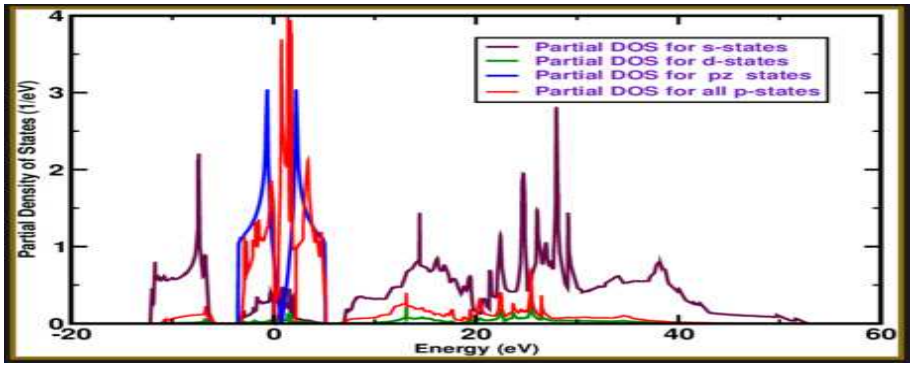
Figure 2: (a) Asymptotic parts of the calculated graphene Green function continued fraction coefficients obtained by recursion for 5% voids and (b) the same for 1% voids.



(a)



(b)



(c)

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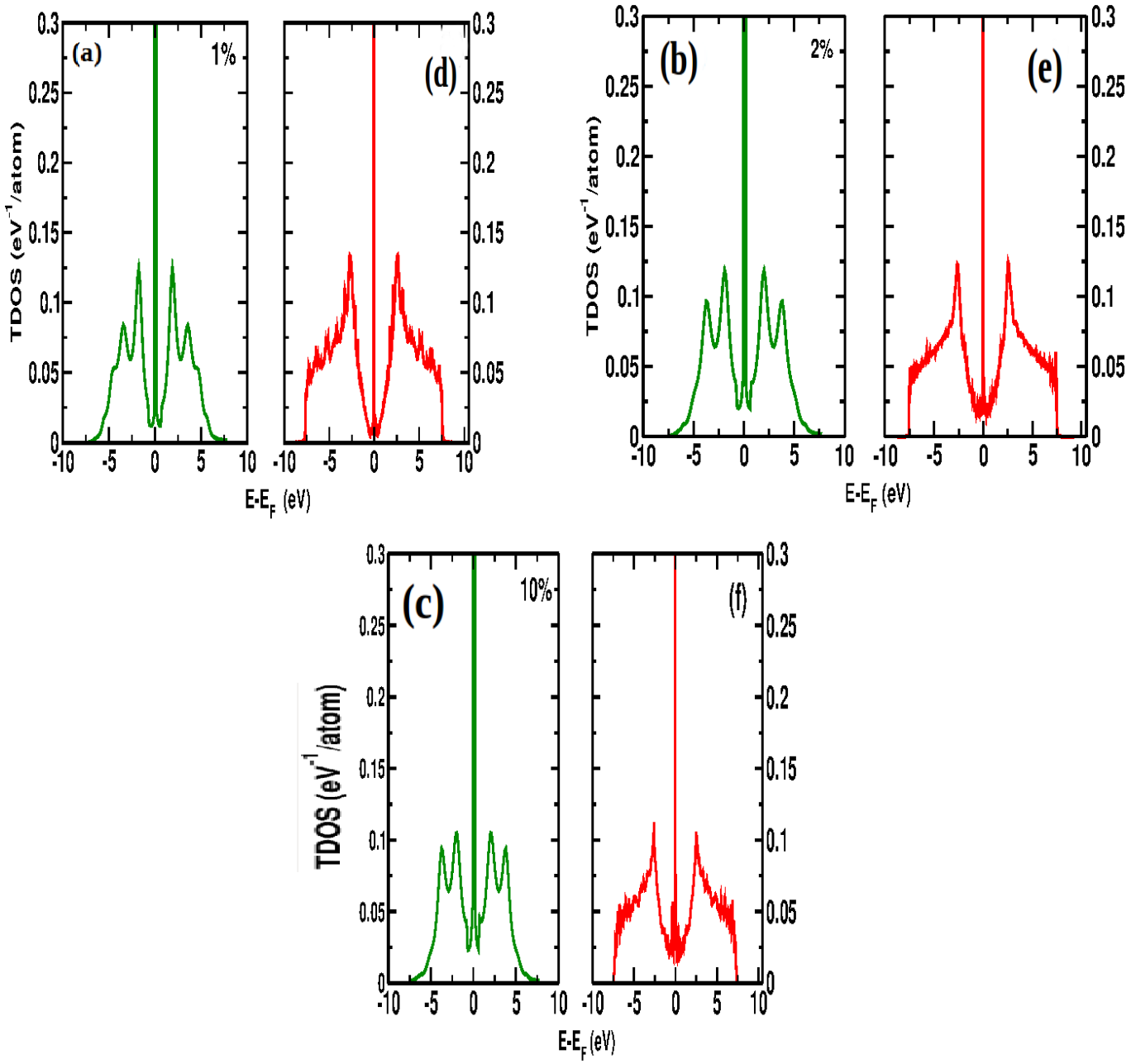

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